# imall

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DMN65D8L

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	Package	Ι <sub>D</sub> T <sub>A</sub> = +25°C
60V	3Ω @ V <sub>GS</sub> = 10V		310mA
60 V	4Ω @ V <sub>GS</sub> = 5V	SOT23	270mA

#### Description

This new generation MOSFET has been designed to minimize the onstate resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### Applications

- DC-DC Converters
- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

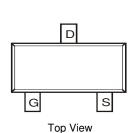
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Solderable per MIL-STD-202, Method 208 3
- Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe).
- Terminal Connections: See Diagram
- Drain Weight: 0.008487 grams (Approximate)



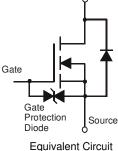


SOT23

**Top View** 



Pin Configuration



#### Ordering Information (Note 4)

Parameter		
Part Number	Case	Packaging
DMN65D8L-7	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www. www.diodes.com/products/packages.html.

#### **Marking Information**

MM6	ΥM

MM6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	201	1	~		2016	20	17	2018		2019	2	2020
Code	Y		~		D			F		G		Н
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	60	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	Ι <sub>D</sub>	310 240	mA
Continuous Drain Current (Note 6) $V_{GS} = 5V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	Ι <sub>D</sub>	270 210	mA
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	800	mA		
Maximum Body Diode Continuous Current (Note 5)	Is	500	mA		

#### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Total Power Dissigation	(Note 6)	P	370	mW	
Total Power Dissipation	(Note 5)	PD	540	11100	
Thermal Desistence, lunction to Ambient	(Note 6)		348		
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ ext{ heta}JA}$	241	°C/W	
Thermal Resistance, Junction to Case	(Note 5)	$R_{\theta JC}$	91		
Operating and Storage Temperature Range	·	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

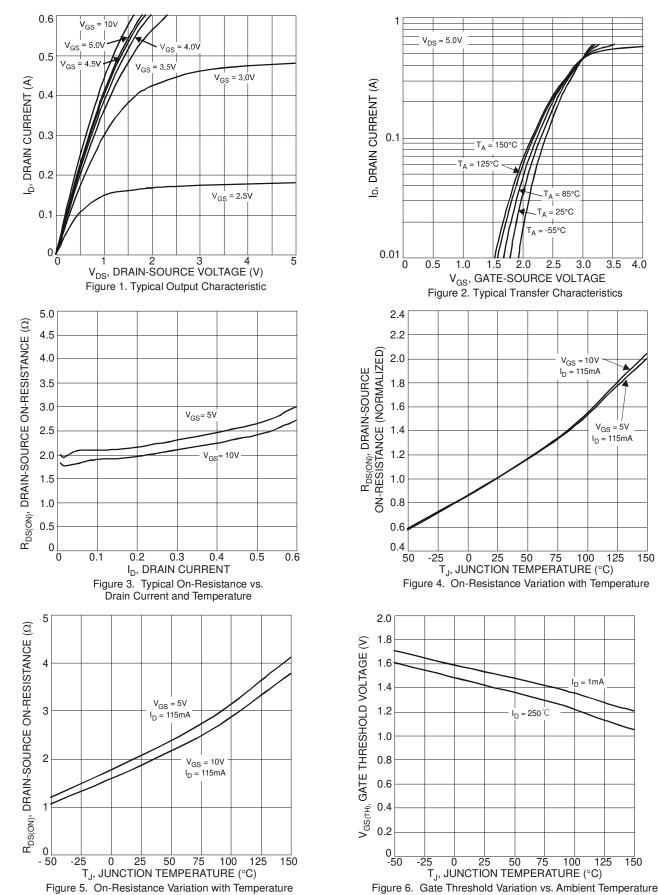
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60			V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	—	_	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Body Leakage	I <sub>GSS</sub>		_	±5	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.2	_	2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	2	3	Ω	$V_{GS} = 10V, I_D = 0.115A$
	R <sub>DS(ON)</sub>		2.5	4	Ω	$V_{GS} = 5V, I_D = 0.115A$
Forward Transconductance	<b>g</b> fs	80	290	_	ms	$V_{DS} = 10V, I_D = 0.115A$
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		22.0			
Output Capacitance	Coss	—	3.2	_	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	C <sub>rss</sub>		2.0			
Gate Resistance	Rg	—	79.9	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge V <sub>GS</sub> = 10V	Qg		0.87	_		
Total Gate Charge V <sub>GS</sub> = 4.5V	Qg	_	0.43	_	nC	$V_{GS} = 10V, V_{DS} = 30V,$
Gate-Source Charge	Qgs	—	0.11	_	no	I <sub>D</sub> = 150mA
Gate-Drain Charge	Q <sub>gd</sub>		0.11	_		
Turn-On Delay Time	t <sub>D(ON)</sub>		2.7			
Turn-On Rise Time	t <sub>R</sub>	_	2.8			$V_{DD} = 30V, I_D = 0.115A, V_{GEN} = 10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		12.6		ns	$R_{GEN} = 25\Omega$
Turn-Off Fall Time	tF		7.3			

Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

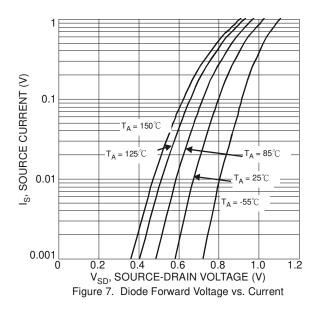
7 .Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to production testing

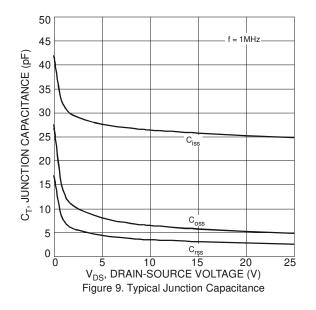




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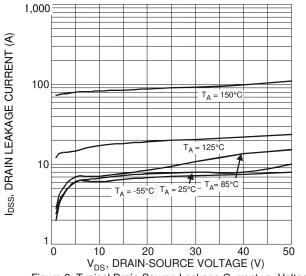
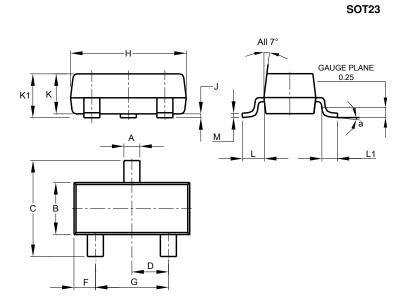


Figure 8. Typical Drain-Source Leakage Current vs. Voltage



#### **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

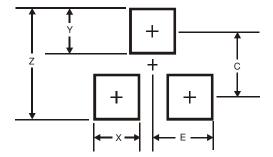


	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
К	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а		8°					
All	Dimens	ions in	mm				

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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